Supporting Information

Hollow Hafnium Oxide (HfO_2) Fibers: Using an Effective Combination of Sol-Gel, Electrospinning, and Thermal Degradation Pathway

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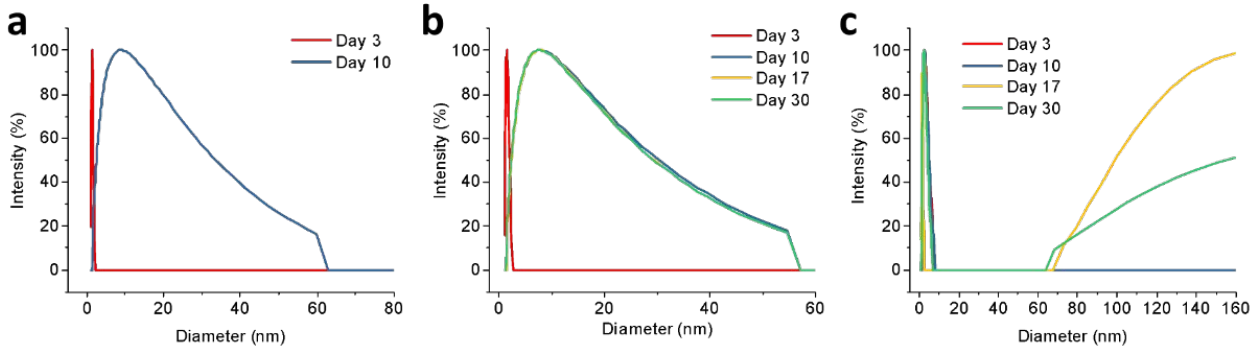

Figure S1. DLS experiments for different storage times with different sol-gel solvents: (a) ethanol at room temperature, (b) ethanol kept at 5 °C, and (c) PGME at room temperature.

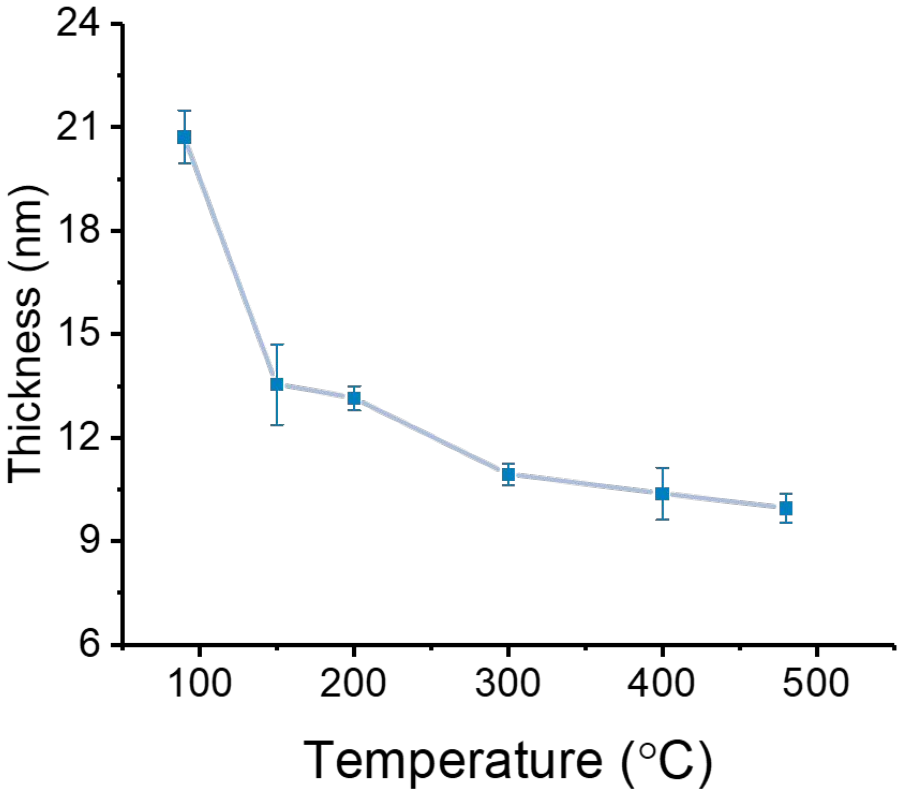

Figure S2. HfO_2 thicknesses in different temperatures on silicon wafers.

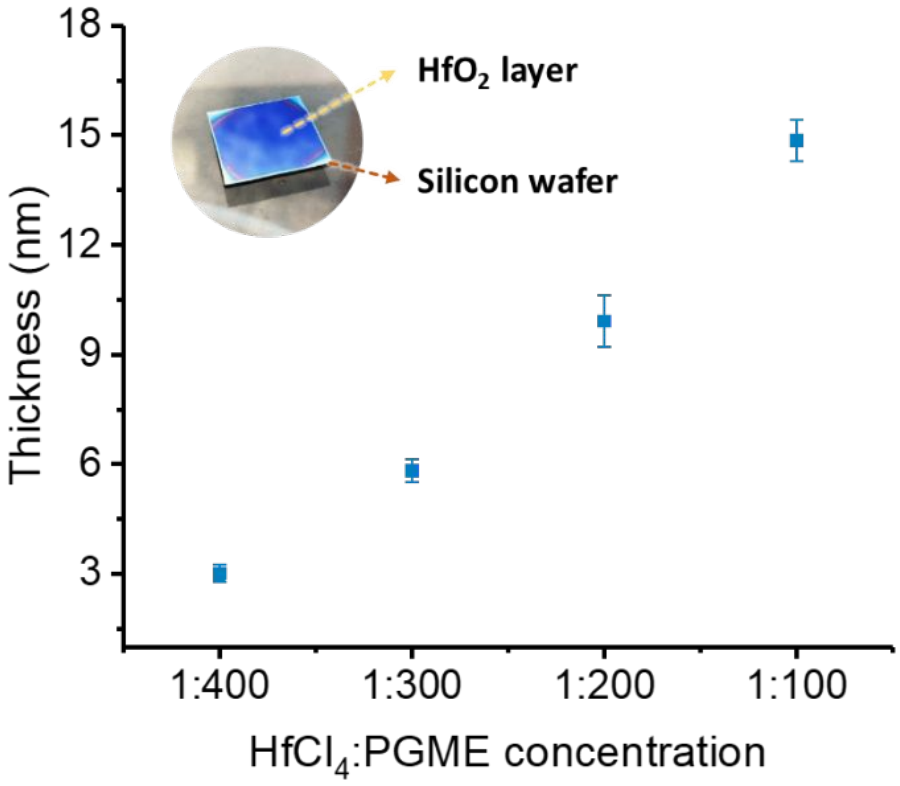

Figure S3. HfO_2 thicknesses at different molar ratios on silicon wafers.

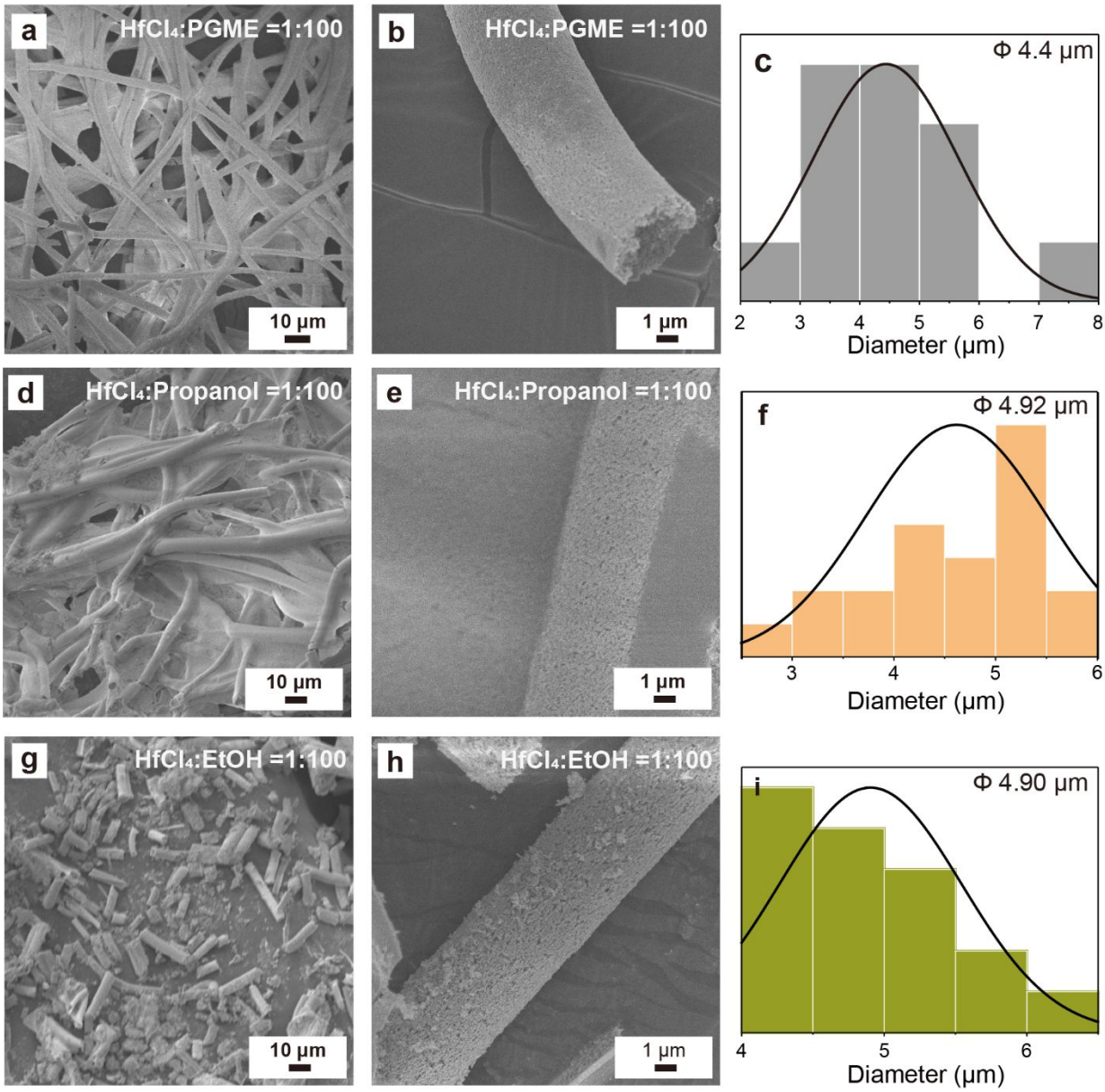

Figure S4. Hollow HfO_2 fibers prepared with different solvents. (a-c) PGME: (a,b) SEM images and (c) fiber diameter distribution. (d-f) Propanol: (d,e) SEM images and (f) fiber diameter distribution. (g-i) Ethanol: (g,h) SEM images and (i) fiber diameter distribution.

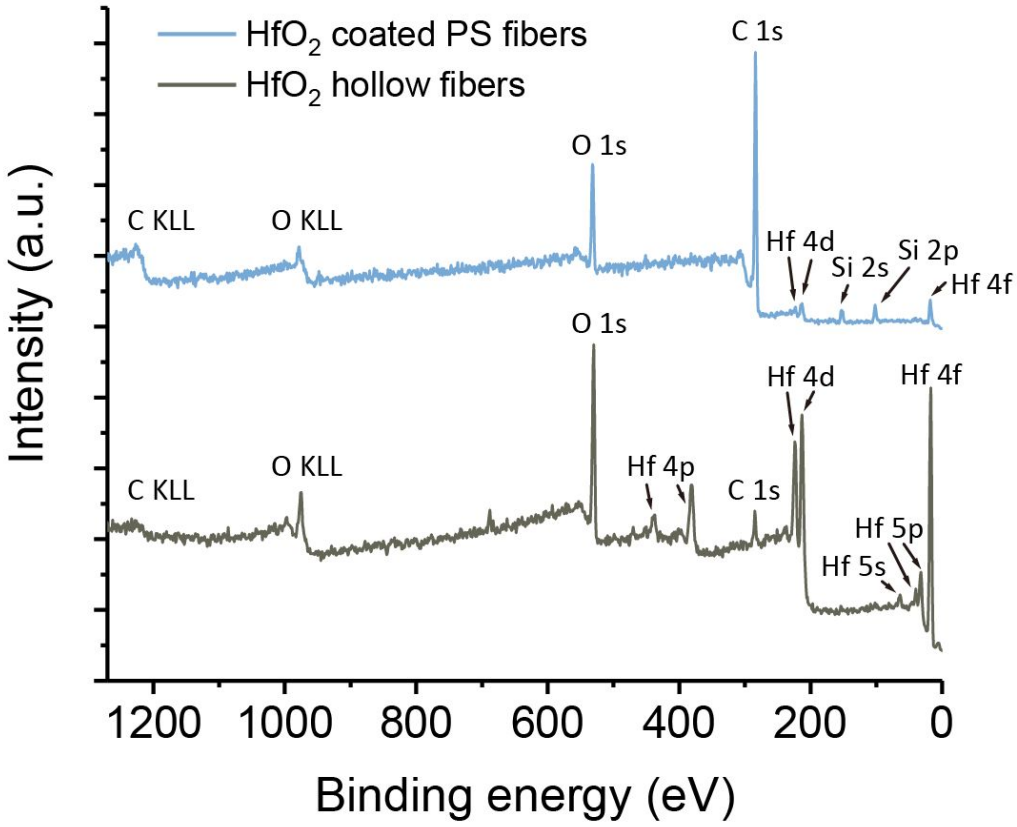

Figure S5. XPS data of the HfO_2 coated PS fibers and HfO_2 hollow fibers.